TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

TA8409S,TA8409F

BRIDGE DRIVER

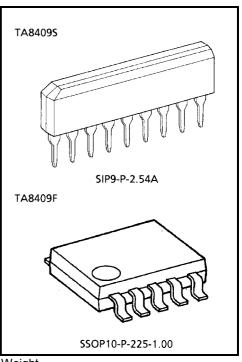
TA8409S and TA8409F are bridge driver with output voltage control.

FEATURES

- Modes available (CW / CCW / STOP / BRAKE)
- Output current up to 0.4 A (AVE) and 1.0 A (PEAK)
- Wide range of operating voltage VCC (opr.) = 4.5~20 V VS (opr.) = 0~20 V

 $V_{ref (opr.)} = 0 \sim 20 \text{ V} \quad (V_{ref} \leq V_S)$

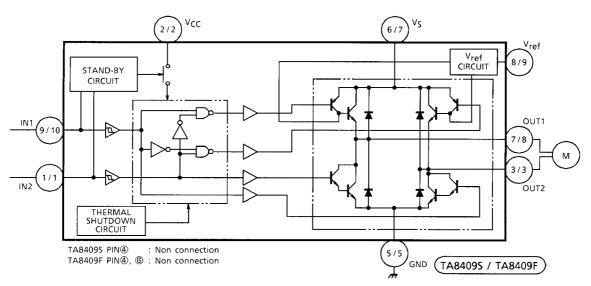
- Built-in thermal shutdown
- Standby mode available (STOP MODE)
- Hysteresis for all inputs.



Weight

SIP9-P-2.54A : 0.92 g (Typ.) SSOP10-P-225-1.00 : 0.09 g (Typ.)

BLOCK DIAGRAM



PIN FUNCTION

TA8409S

PIN No.	SYMBOL	FUNCTIONAL DESCRIPTION			
1	IN2	Input terminal			
2	V _{CC}	Supply voltage terminal for logic			
3	OUT2	Output terminal			
4	NC	Non connection			
5	GND	GND terminal			
6	Vs	Supply voltage terminal for motor driver			
7	OUT1	Output terminal			
8	V _{ref}	Reference voltage terminal for control circuit			
9	IN1	Input terminal			

TA8409F

PIN No.	SYMBOL	FUNCTIONAL DESCRIPTION		
1	IN2	Input terminal		
2	V _{CC}	Supply voltage terminal for logic		
3	OUT2	Output terminal		
4	NC	Non connection		
5	GND	GND terminal		
6	NC	Non connection		
7	VS	Supply voltage terminal for motor driver		
8	OUT1	Output terminal		
9	V _{ref}	Reference voltage terminal for control circuit.		
10	IN1	Input terminal		

FUNCTION

INPUT		OUT	MODE		
IN 1	IN 2	OUT1	OUT2	MB	
0	0	80	80	STOP	
1	0	Н	L	CW / CCW	
0	1	L	Н	CCW / CW	
1	1	L	L	BRAKE	

∞: High impedance

Note: Inputs are all high active type.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Supply Voltage		V _{CC}	25	V	
Motor Drive Voltage		Vs	25	V	
Reference Voltage		V _{ref}	25	V	
Output Current	PEAK	I _{O (PEAK)}	1.0	Α	
	AVE	I _O (AVE.)	0.4		
Power Dissipation	TA8409F	P _D	0.735 (Note)	W	
Power Dissipation	TA8409S	T FD	0.95		
Operating Temperature		T _{opr}	-30~75	°C	
Storage Temperature		T _{stg}	-55~150	°C	

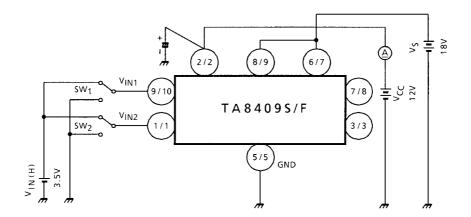
Note: This rating is obtained by mounting on $50 \times 50 \times 1.6$ mm PCB that occupied above 30% of copper area.

ELECTRICAL CHARACTERISTICS (Ta = 25°C, V_{CC} = 12 V, V_S = 18 V)

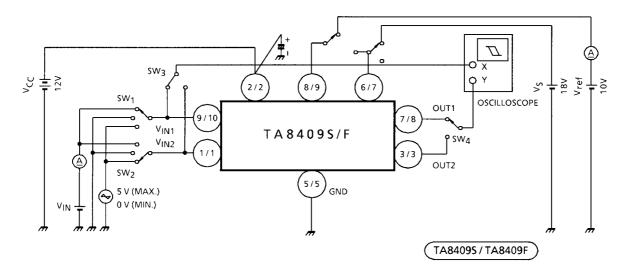
			TEST						
CHARACTERISTIC		SYMBOL	CIR- CUIT	TEST CONDITION	MIN	TYP.	MAX	UNIT	
Supply Current		I _{CC1}	1	Output OFF, CW / CCW mode — 10.0		15.0	mA		
		I _{CC2}	1	Output OFF, STOP mode	_	0	50	μΑ	
		I _{CC3}	1	Output OFF, BREAK mode	_	6.5	10.0	mA	
Input Operating	1 (High)	V _{IN 1}	2	T _j = 25°C IN1, 2	3.5	_	5.5	V	
Voltage	2 (Low)	V _{IN 2}	2	T _j = 25°C IN1, 2	GND	_	0.8	V	
Input Current		I _{IN}	2	Sink mode, V _{IN} = 3.5 V	_	3	10	μΑ	
Input Hysteresis Volta	ge	ΔV_{T}	2	_	_	0.7	1	V	
Saturation Voltage	Upper Side	V _{SAT U-1}	3	$V_{ref} = V_S$, V_{OUT} – V_S measure $I_O = 0.2$ A, CW / CCW mode	_	0.9	1.2	V	
	Lower Side	V _{SAT L-1}	3	$V_{ref} = V_S$, V_{OUT} -GND measure $I_O = 0.2$ A, CW / CCW mode	_	0.8	1.2		
	Upper Side	V _{SAT U-2}	3	V _{ref} = V _S , V _{OUT} -V _S measure I _O = 0.4 A, CW / CCW mode	_	1.0	1.35		
	Lower Side	V _{SAT L-2}	3	V _{ref} = V _S , V _{OUT} -GND measure I _O = 0.4 A, CW / CCW mode	_	0.9	1.35		
Output Voltage		V _{SAT U-1} '	3	V _{ref} = 10 V, V _{OUT} -GND measure I _O = 0.2 A	10.4	11.2	12.2	.,	
		V _{SAT U-2}	3	V _{ref} = 10 V, V _{OUT} -GND measure I _O = 0.4 A	_	10.9	_	V	
Output Transistor Leakage Current	Upper Side	I _{LU}	4	V _L = 25 V	_	_	50		
	Lower Side	ILL	4	V _L = 25 V	_	_	50	μA	
Diode Forward	Upper Side	V _{FU-1}	5	I _F = 0.4 A	_	1.5	_	V	
Voltage	Lower Side	V _{FL-1}	5	I _F = 0.4 A	_	0.9	_		
Reference Current		I _{ref}	2	V _{ref} = 10 V, source mode	_	20	40	μΑ	

TEST CIRCUIT 1

ICC1, ICC2, ICC3

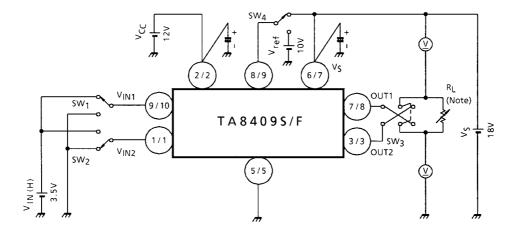


TEST CIRCUIT 2 $V_{IN1}, V_{IN2}, I_{IN}, \Delta V_T, I_{ref}$



TEST CIRCUIT 3

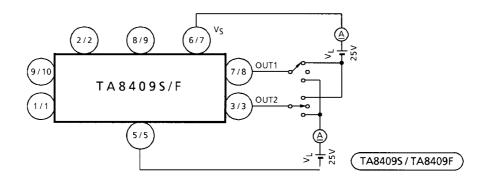
V_{SAT U-1, 2}, V_{SAT L-1, 2}, V_{SAT U-1', 2'}



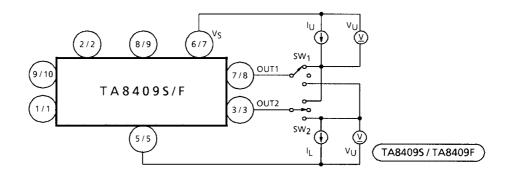
Note: Calibrate I_{OUT} to 0.2 / 0.4 A by R_L.

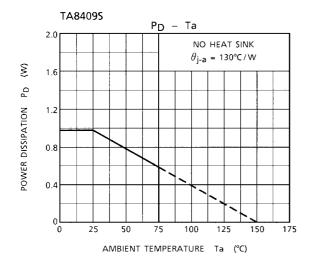
TEST CIRCUIT 4

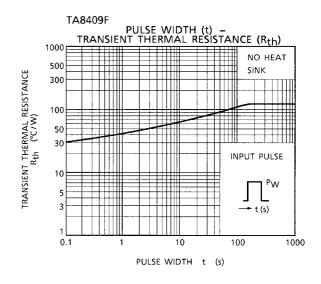
IL U, L

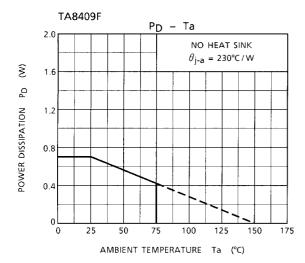


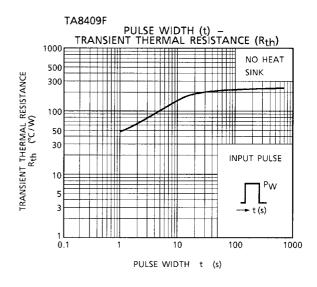
TEST CIRCUIT 5 V_{F U-1, 2}, V_{F L-1, 2}

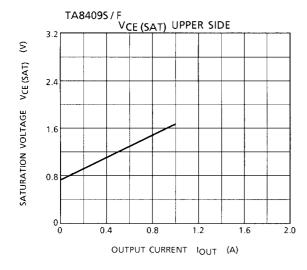


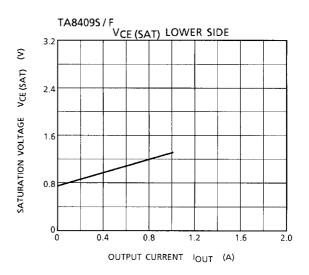




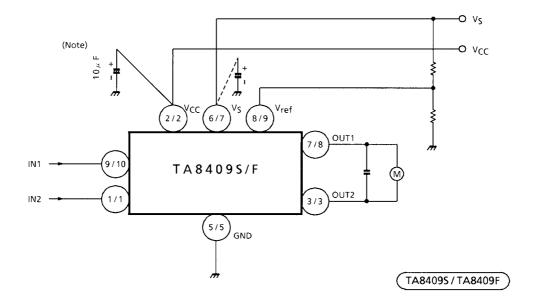








APPLICATION CIRCUIT



- Note 1: Connect if required.
- Note 2: Utmost care is necessary in the design of the output line, V_S and GND line since IC may be destroyed due to short–circuit between outputs, air contamination fault, or fault by improper grounding.

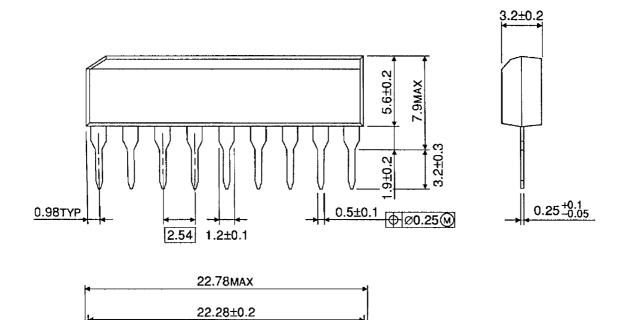
- Note 3: Be careful when switching the input because rush current may occur.

 When switching, stop mode should be entered or current limitation resister R should be inserted.
- Note 4: The IC functions cannot be guaranteed when turning power on of off.

 Before using the IC for application, check that there are no problems.

PACKAGE DIMENSIONS

SIP9-P-2.54A Unit: mm

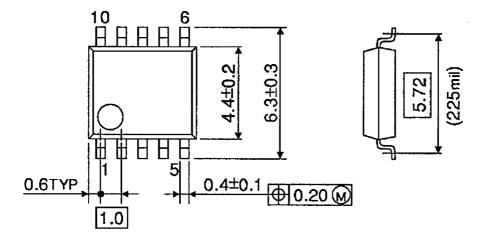


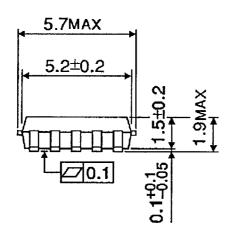
9

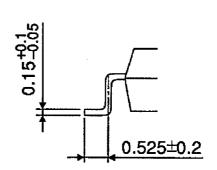
Weight: 0.92 g (Typ.)

PACKAGE DIMENSIONS

SSOP10-P-225-1.00 Unit: mm







Weight: 0.09 g (Typ.)

2001-06-13

RESTRICTIONS ON PRODUCT USE

000707EBA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.